NSN 5961-00-070-6974

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-070-6974
Inclosure Material:
Metal
Overall Length:
0.505 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.562 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
2.3 forward voltage, peak and 3.5 gate trigger voltage, dc
Current Rating Per Characteristic:
150.00 milliamperes source cutoff current minor
Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector peak
Maximum Operating Tempurature Per Measurement Point:
105.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0